

## Chapter 6

# Assignment 6 Solutions

5.1. Find ...

a. ... the minimum wavelength of a GaAlAs source.

b. ... the maximum wavelength of a GaAlAs source.

*Solution:* We know that, for  $0 < x < 0.37$ ,

$$E'_g = 1.424 + 1.266x + 0.266x^2, \quad (6.1)$$

where  $E'_g$  is the bandgap energy in eV and also that

$$\lambda' = \frac{1.240}{E'_g}, \quad (6.2)$$

where  $\lambda'$  is the wavelength in  $\mu\text{m}$ .

a) For  $x = 0.37$ ,

$$\begin{aligned} E'_g &= 1.424 + 1.266x + 0.266x^2 \\ &= 1.424 + (1.266)(0.37) + 0.266(0.37)^2 = 1.929 \text{ eV} \end{aligned} \quad (6.3)$$

and

$$\lambda' = \frac{1.240}{E'_g} = \frac{1.240}{1.929} = 0.643 \mu\text{m} = 643 \text{ nm}. \quad (6.4)$$

b) For  $x = 0.0$ ,

$$\begin{aligned} E'_g &= 1.424 + 1.266x + 0.266x^2 \\ &= 1.424 + (1.266)(0) + 0.266(0)^2 = 1.424 \text{ eV} \end{aligned} \quad (6.5)$$

and

$$\lambda' = \frac{1.240}{E'_g} = \frac{1.240}{1.424} = 0.871 \mu\text{m} = 871 \text{ nm}. \quad (6.6)$$

5.2. Using the alloy fraction formulas, find the material composition for ...

a. ... a 1.3  $\mu\text{m}$  source.

b. ... a 1.55  $\mu\text{m}$  source.

*Solution:* For an InP substrate we know that

$$E'_g = 1.35 - 0.72y + 0.12y^2, \quad (6.7)$$

where  $E'_g$  is the bandwidth energy in eV, and also that

$$\lambda' = \frac{1.240}{E'_g}, \quad (6.8)$$

where  $\lambda'$  is the wavelength in  $\mu\text{m}$ .

a) For  $\lambda' = 1.300$ ,

$$E'_g = \frac{1.240}{\lambda'} = \frac{1.240}{1.300} = 0.954. \quad (6.9)$$

Substituting, we have

$$\begin{aligned} E'_g &= 1.35 - 0.72y + 0.12y^2 & (6.10) \\ 0.954 &= 1.35 - 0.72y + 0.12y^2 \\ 0 &= 0.12y^2 - 0.72y + 0.396. \end{aligned}$$

Solving the quadratic formula, we obtain two solutions for  $y$ . We discard the solution that is greater than 1, and find

$$\begin{aligned} y &= 0.613 & (6.11) \\ 1 - y &= 0.387. \end{aligned}$$

We find  $x$  from

$$x = \frac{0.4526}{1 - 0.031y} = \frac{0.4526}{1 - (0.031)(0.613)} = 0.469 \quad (6.12)$$

and, hence,

$$1 - x = 0.531. \quad (6.13)$$

So the alloy is  $\text{In}_{0.469}\text{Ga}_{0.535}\text{As}_{0.613}\text{P}_{0.387}$  for a 1300 nm source.

b) For  $\lambda' = 1.550$ ,

$$E'_g = \frac{1.240}{\lambda'} = \frac{1.240}{1.550} = 0.800. \quad (6.14)$$

Substituting, we have

$$\begin{aligned} E'_g &= 1.35 - 0.72y + 0.12y^2 & (6.15) \\ 0.800 &= 1.35 - 0.72y + 0.12y^2 \\ 0 &= 0.12y^2 - 0.72y + 0.550. \end{aligned}$$

Solving the quadratic formula, we obtain two solutions for  $y$ . We discard the solution that is greater than 1, and find

$$\begin{aligned} y &= 0.898 \\ 1 - y &= 0.1016. \end{aligned} \quad (6.16)$$

We find  $x$  from

$$x = \frac{0.4526}{1 - 0.031y} = \frac{0.4526}{1 - (0.031)(0.898)} = 0.469 \quad (6.17)$$

and, hence,

$$1 - x = 0.531. \quad (6.18)$$

So the alloy is  $\text{In}_{0.469}\text{Ga}_{0.531}\text{As}_{0.898}\text{P}_{0.1016}$  for a 1550 nm source.

**5.3.** Consider two  $\text{Ga}_{1-x}\text{Al}_x\text{As}$  laser sources with  $x = 0.02$  for the first and  $x = 0.09$  for the other. Find the bandgap energy and peak wavelength for these devices.

*Solution:* We know that for  $0 < x < 0.37$ ,

$$E'_g = 1.424 + 1.266x + 0.266x^2, \quad (6.19)$$

where  $E'_g$  is the bandgap energy in eV and also that

$$\lambda' = \frac{1.240}{E'_g}, \quad (6.20)$$

where  $\lambda'$  is the wavelength in  $\mu\text{m}$ .

a) For  $x = 0.02$ ,

$$\begin{aligned} E'_g &= 1.424 + 1.266x + 0.266x^2 \\ &= 1.424 + (1.266)(0.02) + 0.266(0.02)^2 = 1.449 \text{ eV} \end{aligned} \quad (6.21)$$

and

$$\lambda' = \frac{1.240}{E'_g} = \frac{1.240}{1.449} = 0.855 \mu\text{m} = 855 \text{ nm}. \quad (6.22)$$

b) For  $x = 0.09$ ,

$$\begin{aligned} E'_g &= 1.424 + 1.266x + 0.266x^2 \\ &= 1.424 + (1.266)(0.09) + 0.266(0.09)^2 = 1.540 \text{ eV} \end{aligned} \quad (6.23)$$

and

$$\lambda' = \frac{1.240}{E'_g} = \frac{1.240}{1.540} = 0.805 \mu\text{m} = 805 \text{ nm}. \quad (6.24)$$

**5.4.** We want to estimate the transmission at air–material interfaces for high refractive–index materials like InP and GaAs. For a plane wave at perpendicular incidence, the transmissivity of a planar interface between a material and air ( $n = 1$ ) is

$$T = 1 - \left( \frac{n-1}{n+1} \right)^2, \quad (6.25)$$

where  $n$  is the index of refraction of the material. Find  $T$  in percent and in dB for ...

a. ... InP ( $n = 3.4$ ).

b. ... GaAs ( $n = 3.6$ ).

Solution: a) For  $n = 3.4$ , we have

$$T = 1 - \left( \frac{n-1}{n+1} \right)^2 = 1 - \left( \frac{3.4-1}{3.4+1} \right)^2 = 0.702 \Rightarrow -1.534 \text{ dB} \quad (6.26)$$

or a transmission of 70.2%.

b) For  $n = 3.6$ , we have

$$T = 1 - \left( \frac{n-1}{n+1} \right)^2 = 1 - \left( \frac{3.6-1}{3.6+1} \right)^2 = 0.681 \Rightarrow -1.672 \text{ dB} \quad (6.27)$$

or a transmission of 68.1%.

**5.5.** Show that the LED bandwidth is given by Eq. 5.20 on page 121.

*Solution:* We begin with the equation for the optical power

$$P_{\text{out}} = \frac{P_0}{1 + 4\pi^2 f^2 \tau_{\text{lifetime}}^2}. \quad (6.28)$$

We want to find the frequency  $f_{3\text{-dB}}$  that makes  $P_{\text{out}} = P_0/2$ , so

$$\begin{aligned} \frac{P_{\text{out}}}{P_0} &= \frac{1}{2} = \frac{1}{1 + 4\pi^2 f_{3\text{-dB}}^2 \tau_{\text{lifetime}}^2} & (6.29) \\ 2 &= 1 + 4\pi^2 f_{3\text{-dB}}^2 \tau_{\text{lifetime}}^2 \\ 1 &= 4\pi^2 f_{3\text{-dB}}^2 \tau_{\text{lifetime}}^2 \\ f_{3\text{-dB}}^2 &= \frac{1}{4\pi^2 \tau_{\text{lifetime}}^2} \\ f_{3\text{-dB}} &= \frac{1}{2\pi \tau_{\text{lifetime}}}. \end{aligned}$$

**5.6** An optical source is selected from group of devices specified as requiring a mean time of  $5 \times 10^4$  hours for the output power to degrade by  $-3$  dB. If the device emits 5 mW at room

temperature at the start of a test, what will be its emission power after (a) 1 month, (b) 1 year, (c) 5 years and (d) 10 years?

*Solution:* The long-term power behavior of a laser is

$$P = P_0 e^{(-t/\tau_m)}. \quad (6.30)$$

We begin by calculating  $\tau_m$ , from

$$\begin{aligned} P &= P_0 e^{(-t/\tau_m)} \\ \frac{P}{P_0} &= 0.5 = e^{(-5 \times 10^4 / \tau_m)} \\ \tau_m &= \frac{5 \times 10^4}{\ln(0.5)} = 7.21 \times 10^4 \text{ hrs.} \end{aligned} \quad (6.31)$$

a. For  $t = 1$  month  $= 1(30)(24) = 720$  hours,

$$P = P_0 e^{(-t/\tau_m)} = 5 e^{(-720/(7.21 \times 10^4))} = 4.95 \text{ mW}. \quad (6.32)$$

b. For  $t = 1$  year  $= (1)(365)(24) = 8.76 \times 10^3$  hours,

$$P = P_0 e^{(-t/\tau_m)} = 5 e^{(-(8.76 \times 10^3)/(7.21 \times 10^4))} = 4.43 \text{ mW}. \quad (6.33)$$

c. For  $t = 5$  years  $= (5)(365)(24) = 4.38 \times 10^4$  hours,

$$P = P_0 e^{(-t/\tau_m)} = 5 e^{(-(4.38 \times 10^4)/(7.21 \times 10^4))} = 2.72 \text{ mW}. \quad (6.34)$$

d. For  $t = 10$  years  $= (10)(365)(24) = 8.76 \times 10^4$  hours,

$$P = P_0 e^{(-t/\tau_m)} = 5 e^{(-(8.76 \times 10^4)/(7.21 \times 10^4))} = 1.484 \text{ mW}. \quad (6.35)$$

**5.7.** A group of laser devices has an operating lifetime of  $3.5 \times 10^4$  at 60C and 6700 hours at 90C. Find the activation energy for these devices and calculate the expected lifetime at 20C.

*Solution:* We have  $\tau_1 = 3.5 \times 10^4$  hours for  $T = 60\text{C} = 330\text{K}$  and  $\tau_2 = 6.7 \times 10^3$  hrs for  $T = 90\text{C} = 360\text{K}$ .

To find the activation energy  $E$ , we find

$$\begin{aligned} \frac{\tau_1}{\tau_2} &= \frac{e^{\frac{E}{kT_1}}}{e^{\frac{E}{kT_2}}} \\ &= e^{\frac{E}{k} \left( \frac{1}{T_1} - \frac{1}{T_2} \right)} \end{aligned} \quad (6.36)$$

$$\ln\left(\frac{\tau_1}{\tau_2}\right) = \frac{E}{k} \left( \frac{1}{T_1} - \frac{1}{T_2} \right) \quad (6.37)$$

$$\begin{aligned} E &= k \ln\left(\frac{\tau_1}{\tau_2}\right) \frac{1}{\left(\frac{1}{T_1} - \frac{1}{T_2}\right)} \quad (6.38) \\ &= (1.38 \times 10^{-23}) \ln\left(\frac{3.5 \times 10^4}{6.7 \times 10^3}\right) \frac{1}{\left(\frac{1}{330} - \frac{1}{360}\right)} \\ &= 9.05 \times 10^{-20} \text{ joules} \Rightarrow 0.566 \text{ eV}. \end{aligned}$$

We want to calculate the expected lifetime at  $T = 20\text{C} = 290\text{K}$ . We find this from

$$\begin{aligned} \frac{\tau_1}{\tau_3} &= \exp\left(\frac{E}{k} \left( \frac{1}{T_1} - \frac{1}{T_3} \right)\right) \quad (6.39) \\ \tau_3 &= \frac{\tau_1}{\exp\left(\frac{E}{k} \left( \frac{1}{T_1} - \frac{1}{T_3} \right)\right)} \\ &= \frac{3.5 \times 10^4}{\exp\left(\frac{9.05 \times 10^{-20}}{1.38 \times 10^{-23}} \left( \frac{1}{330} - \frac{1}{290} \right)\right)} = 5.43 \times 10^5 \text{ hrs}. \end{aligned}$$

**5.8.** A laser diode has a lateral beam divergence of 30 degrees (full angle) and a perpendicular (to the emitting junction) beam divergence of 60 degrees. What are the values of  $L$  and  $T$  associated with this beam pattern?

*Solution:* The asymmetric beam pattern is given by

$$B(\theta, \phi) = \frac{1}{\left(\frac{\sin^2 \phi}{B_0 \cos^T \theta} + \frac{\cos^2 \phi}{B_0 \cos^L \theta}\right)}. \quad (6.40)$$

We want to find  $T$  and  $L$ .

We observe that, when  $\phi = 0$ ,  $B(\theta, 0) = B_0 \cos^L \theta$ . From the definition of beam divergence, we have

$$\begin{aligned} \frac{B(\pm 15^\circ, 0^\circ)}{B_0} &= \frac{1}{2} \quad (6.41) \\ \cos^L 15^\circ &= \frac{1}{2} \\ (0.966)^L &= 0.5 \\ L \ln(0.966) &= \ln(0.5) \\ L &= \frac{\ln(0.5)}{\ln(0.966)} = 20.03 \end{aligned}$$

We also observe that, when  $\phi = 90^\circ$ ,  $B(\theta, 90^\circ) = B_0 \cos^T \theta$ , and

$$\begin{aligned}\frac{B(\pm 30^\circ, 90^\circ)}{B_0} &= \frac{1}{2} \\ \cos^T 30^\circ &= \frac{1}{2} \\ (0.866)^T &= 0.5 \\ T \ln(0.866) &= \ln(0.5) \\ T &= \frac{\ln(0.5)}{\ln(0.866)} = 4.81\end{aligned}\tag{6.42}$$

